## Photointerrupter, General type

## Absolute maximum ratings (Ta=25°C)

	Parameter	Symbol	Limits	Unit
Input (LED)	Forward current	lF	50	mA
	Reverse voltage	VR	5	V
	Power dissipation	Po	80	mW
Output (photo- (transistor)	Collector-emitter voltage	Vceo	30	V
	Emitter-collector voltage	VECO	4.5	V
	Collector current	lc	30	mA
	Collector power dissipation	Pc	80	mW
Operating temperature		Topr	-25 to +85	°C
Storage temperature		Tstg	-40 to +85	°C
	Soldering temperture	Tsol	260 / 3 *	°C / s

\* 1mm from the body bottom.

## Electrical and optical characteristics (Ta=25°C)

Parameter			Symbol	Min.	Тур.	Max.	Unit	Conditions
Input charac- teristics	Forward voltage		VF	-	1.3	1.6	V	I⊧=50mA
	Reverse current		IR	-	-	10	μΑ	VR=10V
Output charac- teristics	Dark current		ICEO	-	-	0.5	μΑ	Vce=10V
	Peak sensitivity wavelength		λρ	-	800	-	nm	-
Transfer characteristics	Collector current		lc	0.5	-	-	mA	Vce=5V, IF=20mA
	Collector-emitter saturation voltage		VCE(sat)	-	0.1	0.5	V	IF=20mA, Ic=0.1mA
	Response time	Rise time	tr	-	10	-	μs	Vcc=5V, IF=20mA, RL=100Ω
		Fall time	tf	-	10	-	μs	
Infrared light emitter diode	Cut-off frequency		fc	-	1	-	MHz	Ir=50mA * Non-coherent Infrared light emitting diode used.
	Peak light emitting wavelength		λρ	-	950	-	nm	
Photo transistor	Response time		tr • tf	-	10	-	μs	$\label{eq:Vcc=5V, lc=1mA, Rl=100\Omega} $$ $$ This product is not designed to be protected against electromagnetic wave. $$$
	Maximum sensitivity wavelength		λp	I	800	-	nm	_

## Electrical and optical characteristics curves

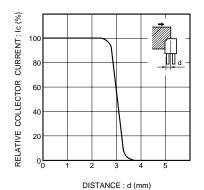


Fig.1 Relative output vs. distance (I)

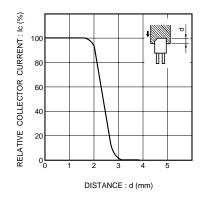


Fig.4 Relative output vs. distance (II)

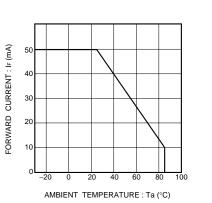
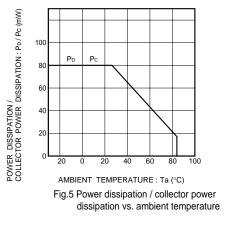
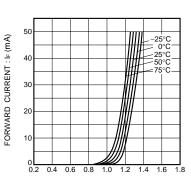


Fig.2 Forward current falloff

6

NO





Applications

AV equipment

Features

Quick response time.

2) Small gap (0.5mm) and good accuracy.

FORWARD VOLTAGE : VF (V)

#### Fig.3 Forward current vs. forward voltage

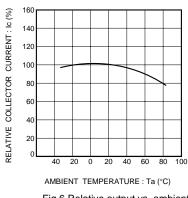
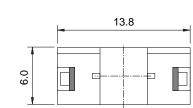
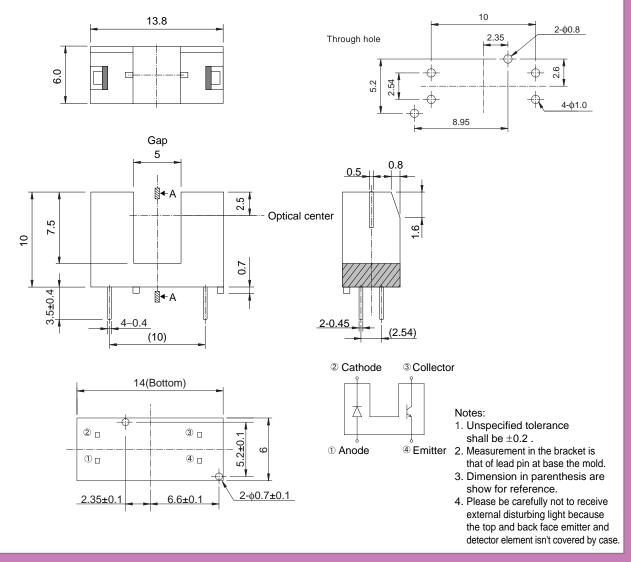
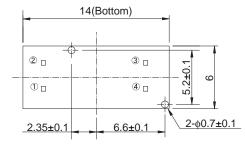


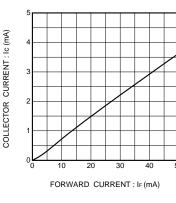
Fig.6 Relative output vs. ambient temperature

## External dimensions (Unit : mm)









C

RENT

E

Fig.7 Collector current vs. forward current

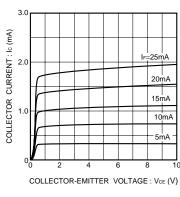
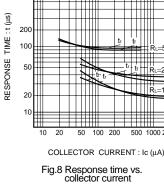
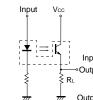


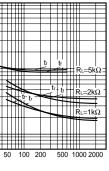
Fig.10 Output characteristics





t₀: Delay time tr: Rise time (time for output current to rise

from 10% to 90% of peak current) tr: Fall time (time for output current to fall



CURRENT

DARK





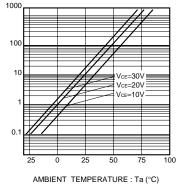
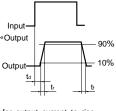


Fig.9 Dark current vs. ambient temperature



from 90% to 10% of peak current)

Fig.11 Response time measurement circuit

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